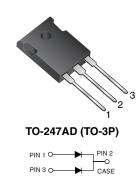


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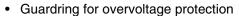
Dual Common-Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS						
I _{F(AV)}	40 A					
V _{RRM}	35 V to 60 V					
I _{FSM}	400 A					
V _F	0.55 V, 0.60 V					
T _J max.	175 °C					

FEATURES





- · Lower power losses, high efficiency
- · Low forward voltage drop
- · High forward surge capability
- · High frequency operation
- Solder dip 260 °C, 40 s
- · Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	MBR40H35PT	MBR40H45PT	MBR40H50PT	MBR40H60PT	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	V		
Maximum working peak reverse voltage	V_{RWM}	35	45	50	60	V		
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V		
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	40						
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, L = 10 mH	E _{AS}	80						
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	400						
Peak repetitive reverse surge current per diode (1)	I _{RRM}	2.0 1.0			Α			
Peak non-repetitive reverse energy (8/20 µs waveform)	E _{RSM}	30 25			25	mJ		
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k Ω	V _C	25						
Voltage rate of change at (rated V _R)	dV/dt	10 000						
Operating junction temperature range	T _J	- 65 to + 175				°C		
Storage temperature range	T _{STG}	- 65 to + 175				°C		

Note:

(1) 2.0 μ s pulse width, f = 1.0 kHz

New Product MBR40H35PT thru MBR40H60PT

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL		MBR40H35PT MBR40H45PT		MBR40H50PT MBR40H60PT	
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 20 A I _F = 20 A I _F = 40 A I _F = 40 A	$T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$ $T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$	V _F	- 0.49 - 0.62	0.63 0.55 0.73 0.66	- 0.56 - 0.68	0.69 0.60 0.83 0.72	>
Maximum reverse current at rated V _R per diode ⁽²⁾		T _J = 25 °C T _J = 125 °C	I _R	- 9.0	150 25	- 6.0	150 25	μA mA

Notes:

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	MBR40H35PT MBR40H45PT MBR40H50PT MBR40H60PT UN						
Thermal resistance, junction to case per diode	$R_{ heta JC}$	1.2			°C/W			

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	D P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY N						
TO-247AD	MBR40H45PT-E3/45	6.13	45	30/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

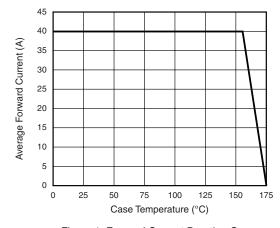


Figure 1. Forward Current Derating Curve

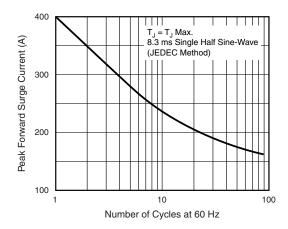


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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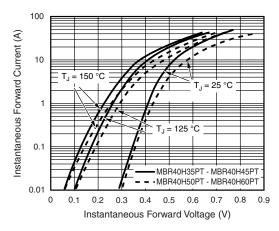


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

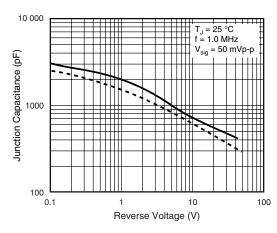


Figure 5. Typical Junction Capacitance Per Diode

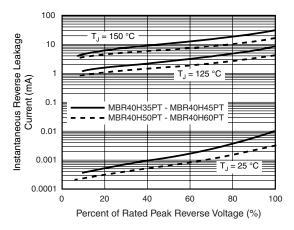


Figure 4. Typical Reverse Characteristics Per Diode

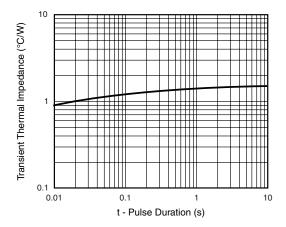
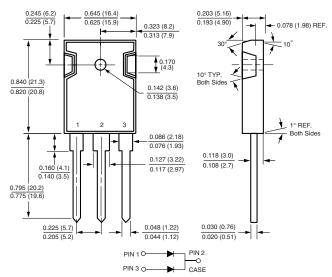


Figure 6. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-247AD (TO-3P)





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